

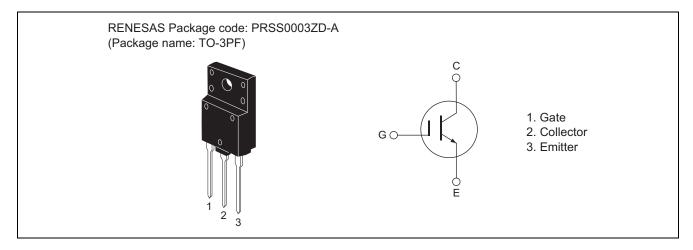
RJP65T54DPM-E0

650V - 30A - IGBT Application: Partial switching circuit R07DS1307EJ0100 Rev.1.00 Nov 02, 2015

Features

- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.35 \text{ V}$ typ. (at $I_C = 30 \text{ A}$, $V_{GE} = 15 \text{ V}$, $Ta = 25^{\circ}\text{C}$)
- Isolated package
- Trench gate and thin wafer technology (G7H series)
- High speed switching
- Operation frequency ($50Hz \le f < 20kHz$)

Outline



Absolute Maximum Ratings

 $(Tc = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage		V _{CES}	650	V
Gate to emitter voltage		V _{GES}	±30	V
Collector current	Tc = 25 °C	lc	60	Α
	Tc = 100 °C	lc	30	Α
Collector peak current		ic(peak) Note1	225	Α
Collector dissipation		Pc	55.5	W
Junction to case thermal impedance		θј-с	2.7	°C/W
Junction temperature		Tj Note2	175	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Please use this device in the thermal conditions which the junction temperature does not exceed 175°C. Renesas IGBT Application Note is disclosed about reliability test and application condition up to 175°C.

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

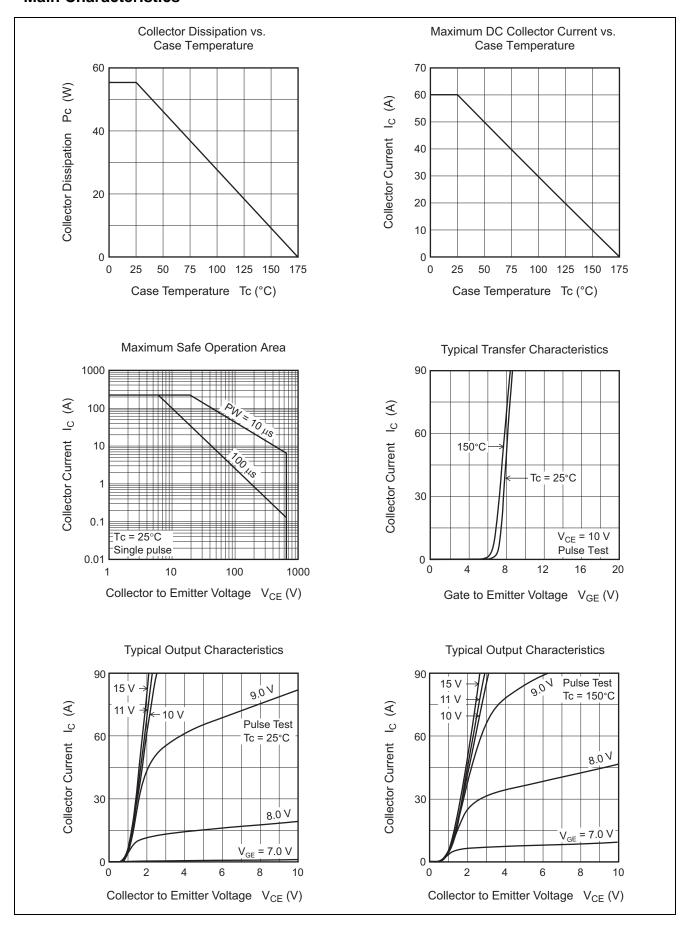
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Zero gate voltage collector current	I _{CES}	_	_	1	μΑ	$V_{CE} = 650 \text{ V}, V_{GE} = 0$	
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	V _{GE(off)}	5	_	7	V	$V_{CE} = 10V, I_{C} = 1.0 \text{ mA}$	
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.35	1.68	V	Ic = 30 A, V _{GE} = 15V Note3	
Total gate charge	Qg		72		nC	V _{CE} = 400 V V _{GE} = 15V	
Gate to emitter charge	Qge		10		nC		
Gate to collector charge	Qgc		30		nC	Ic= 30A	
Input capacitance	Cies	_	1500	_	pF	V _{CE} = 25 V V _{GE} = 0	
Output capacitance	Coes	_	42	_	pF		
Reveres transfer capacitance	Cres	_	30	_	pF	f = 1 MHz	
Turn-on delay time	t _{d(on)}	_	35	_	ns	Vcc = 400 V	
Rise time	tr	_	20	_	ns	$V_{GE} = 15 \text{ V}, \text{ Ic} = 30 \text{ A}$ $Rg = 10 \Omega, \text{ Tc} = 25 \text{ °C}$	
Turn-off delay time	t _{d(off)}	_	105	_	ns		
Fall time	t _f	_	125	_	ns	Inductive load Note4	
Turn-on loss energy	Eon	_	0.33	_	mJ		
Turn-off loss energy	E _{off}	_	0.68	_	mJ		
Turn-on delay time	t _{d(on)}	_	33	_	ns	Vcc = 400 V	
Rise time	tr	_	23	_	ns	V _{GE} = 15 V, I _C = 30 A Rg = 10 Ω, T _C = 150°C	
Turn-off delay time	t _{d(off)}	_	110	_	ns		
Fall time	t _f	_	155		ns	Inductive load Note4	
Turn-on loss energy	Eon	_	0.48		mJ		
Turn-off loss energy	E _{off}	_	0.96	_	mJ		

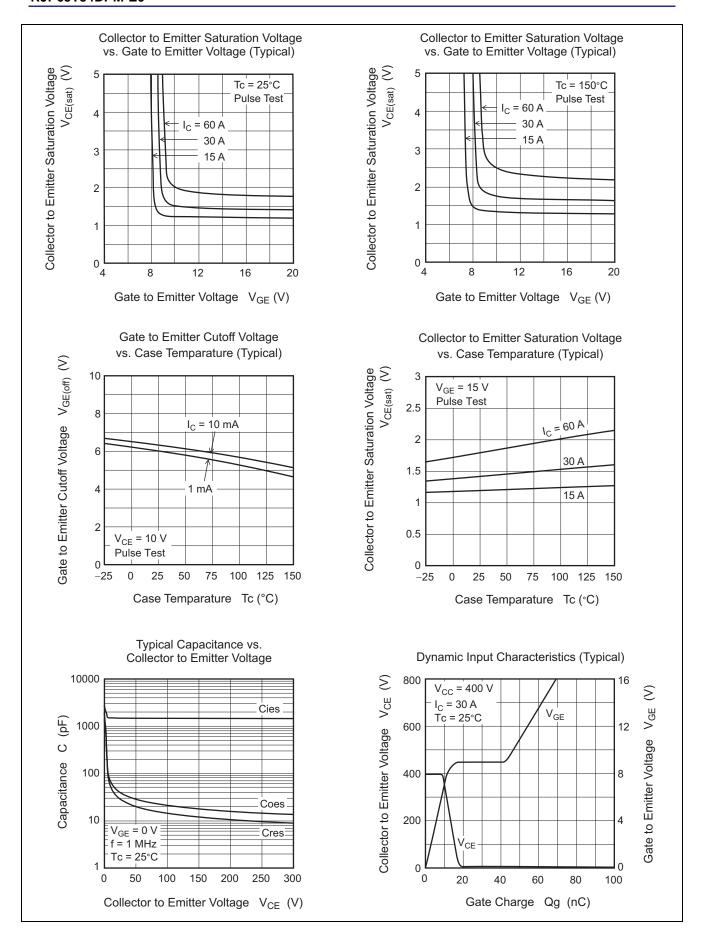
Notes: 3. Pulse test

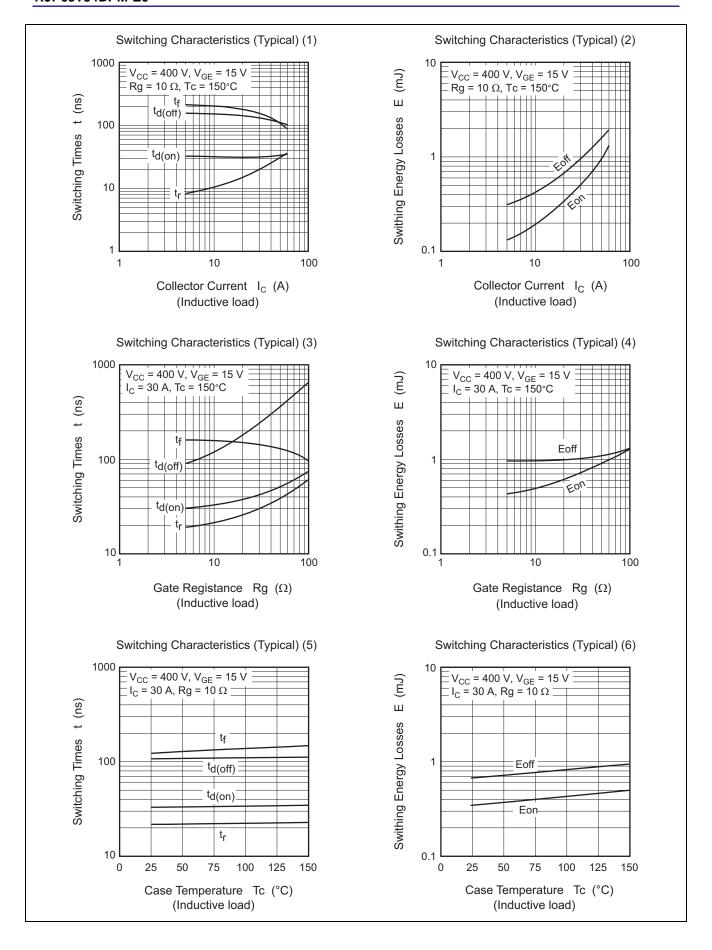
4. Switching time test circuit and waveform are shown below.

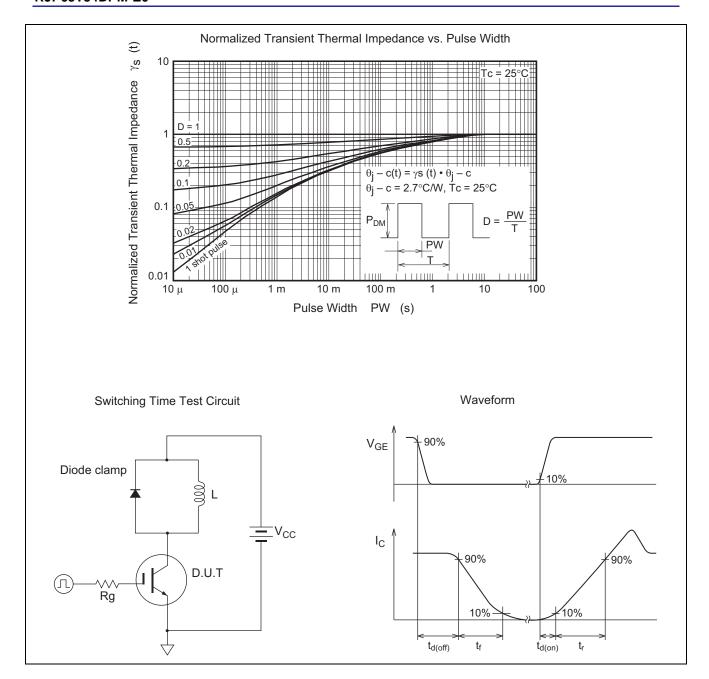
Not guarantee short circuit withstand time

Main Characteristics

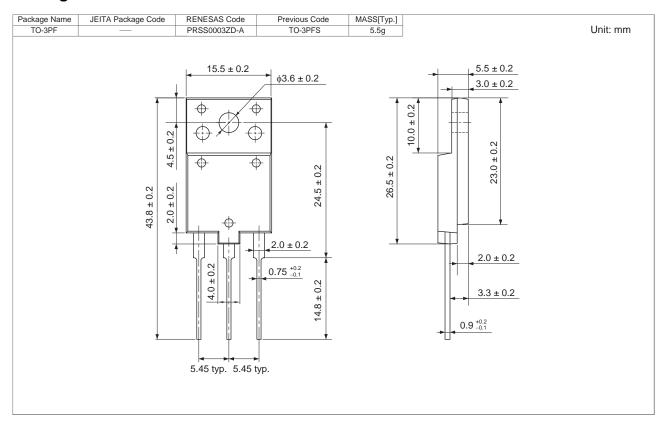








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container	
RJP65T54DPM-E0#T2	360 pcs	Box (Tube)	

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